

**MRL-III-660R** /1~200mW

### RED DIODE LASER At 660nm





Diode red laser 660nm is made features of ultra compact, long lifetime, low cost and easy operating, which is widely used in measurement, spectrum analysis, laser lighting show, etc.



#### SPECIFICATIONS

Wavelength (nm)	660 ± 5		
Output power (mW)	>1, 10, 30, ... , 200		
Energy distribution	Even		
Beam Spot	Round		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
Beam divergence, full angle (mrad)	<8.0		
Dimensions of beam at the aperture (mm)	~2.0		
Beam height from base plate (mm)	24.8		
Operating temperature (°C)	10~35		
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty	1 year		



MxL-III -660	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
 139(L)×73(W)×46.2(H) mm <sup>3</sup> , 0.6kg	 153 (L) ×155(W) ×92 (H) mm <sup>3</sup> , 1.5kg	 133 (L) ×130(W) ×65 (H) mm <sup>3</sup> , 1.2kg	 100 (L) ×62(W) ×56 (H) mm <sup>3</sup> , 0.2kg
